Ceramic Discrete Surface Mount Emitters and Detectors

SME/SMD Series

FEATURES

- Small package size
- Glass lensed optics for efficient optical coupling
- Upright or inverted mounting capability
- Low profile, small size for flexible layout of multiple channels and custom arrays
- Compatible with automated solder processes:
 - IR reflow
 - vapor phase
 - solder wave
 - convection oven
- Choice of photodiode or phototransistor detectors
- IRED features high power dissipation capability
- Tape and reel packaging option – pick and place machine compatible

APPLICATIONS

- Optical encoders for motion control
- · Computer peripherals
- Vending and point-of-sale applications
- Smoke detectors
- Medical equipment



The SME2470, SMD2440 and SMD2420 Series surface mount infrared components are small ceramic packages (0.15 x 0.10 x 0.083 in. / 3,81 x 2,54 x 2,1 mm) with glass lenses. The lens minimizes cross talk and often eliminates the need for apertures in non-critical applications. The low profile components may be mounted on the printed circuit board, lens up or inverted, allowing flexibility in layouts for multiple channel and custom arrays. When mounted lens down over a hole in the PC board, the lens is hidden, lowering overall package height.

The SME2470 is a high intensity aluminum gallium arsenide infrared emitting diode (IRED) which can be used with either the SMD2440 phototransistor or the SMD2420 photodiode. It supplies optimum optical characteristics and efficient optical coupling. The small size and high power dissipation properties of the IRED promote PC board miniaturization and high density placement.

The SMD2440 Series phototransistor's gain characteristics make it useful for applications requiring high responsivity. The SMD2420 Series photodiode is especially useful in applications requiring linear response or high switching speed.

These components are available in bulk, or on tape and reel for use with automatic placement equipment.

Ceramic Discrete Surface Mount

SME/SMD Series

SME2470 SERIES IRED ABSOLUTE MAXIMUM RATINGS

| Power dissipation @ 25 °C* | 150 mW |
|--------------------------------------|---------------------------------|
| Continuous forward current | 75 mA (mounted on a PC board) |
| Reverse voltage ($I_F = 10 \mu A$) | 3 V |
| Operating free air temperature range | -55° to +125°C (-67° to +257°F) |
| Storage temperature | -65° to +150°C (-85° to +302°F) |
| Soldering temperature | 260°C (500°F), 5 seconds max. |

STRESS DAMAGE

CAUTION

Functional operation of the device at or above "Absolute Maximum Ratings" for extended periods of time may affect reliability.

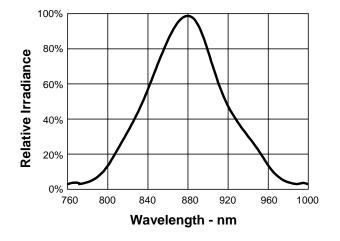
Failure to comply with these instructions may result in product damage.

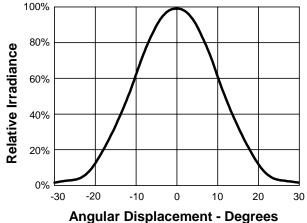
SME2470 SERIES IRED ELECTRICAL CHARACTERISTICS (at 25°C unless otherwise noted)

| Parameter | Test Conditions | Sym. | Min. | Тур. | Max. | Units |
|---------------------------|---|-----------------|------|------|------|--------|
| Irradiance | Measured into 0.104 in. (2.64 mm) dia. aperture @ 0.535 in. (13.59 mm) from lens tip. $I_F = 50$ mA | Н | 0.6 | | | mW/cm² |
| Forward voltage | $I_F = 50 \text{ mA}$ | V _F | | 1.5 | 1.8 | Volts |
| Reverse breakdown voltage | I _R = 10 μA | BV _R | 3.0 | | | Volts |
| Peak output wavelength | $I_F = 50 \text{ mA}$ | λ | | 880 | | nm |
| Spectral bandwidth | I _F = 50 mA | | | 80 | | nm |
| Rise time | 10 µsec pulse width | t _R | | 800 | | ns |
| Fall time | | t _F | | 700 | | ns |

TYPICAL IRED PERFORMANCE CHARACTERISTICS SME2470 Spectral Bandwidth

SME2470 Irradiance vs Angular Displacement





^{*}Derate 1.43 mW/°C above 25°C ambient.

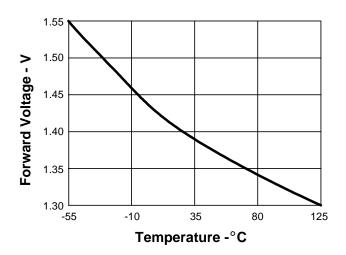
Ceramic Discrete Surface Mount

TYPICAL IRED PERFORMANCE CHARACTERISTICS (when solder mounted to PC board)

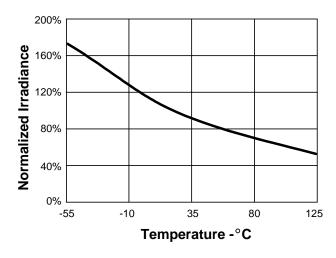
SME2470 Forward Current vs Forward Voltage

1.6 1.5 Forward Voltage - V 1.4 1.3 1.2 1.0 40 60 80 100 20 Forward Current - mA

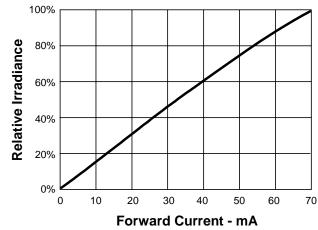
SME2470 Forward Voltage vs Temperature



SME2470 Irradiance vs Temperature



SME2470 Irradiance vs Forward Current



Ceramic Discrete Surface Mount

SME/SMD Series

SMD2440 SERIES PHOTOTRANSISTOR ABSOLUTE MAXIMUM RATINGS

| Collector-Emitter voltage | 30 V |
|--------------------------------|---------------------------------|
| Emitter-Collector voltage | 5 V |
| Continuous device dissipation* | 125 mW |
| Operating free air range | -55° to +125°C (-67° to +257°F) |
| Storage temperature | -65° to +150°C (-85° to +302°F) |
| Soldering temperature | 260°C (500°F), 5 seconds max. |

^{*}Derate 1.43 mW/°C above 25°C ambient.

SMD2440 SERIES PHOTOTRANSISTOR ELECTRICAL CHARACTERISTICS

| Parameter | | Test Conditions | Sym. | Min. | Тур. | Max. | Units |
|--------------------|-------------|---|----------------------|------|------|------|-------|
| Light current | -0X1 | $V_{CE} = 5 \text{ V, H} = 1 \text{ mW/cm}^2,$ | I _L | 1.5 | | 4.0 | mA |
| | -0X2 | 880 nm light source | | 3.0 | | 8.0 | mA |
| Dark current | | V _{CE} = 10 V, H = 0 | I _D | | | 100 | nA |
| Collector breakd | own voltage | $I_{c} = 100 \mu A, H = 0$ | BV _{CEO} | 30 | | | Volts |
| Emitter breakdov | vn voltage | $I_{E} = 100 \ \mu A, \ H = 0$ | BV _{ECO} | 5 | | | Volts |
| Saturation voltage | je (C to E) | $I_{c} = 0.04 \text{ mA}, H = 1 \text{ mW/cm}^{2}$ | V _{CE(SAT)} | | 0.2 | 0.4 | Volts |
| Peak response v | vavelength | | λ | | 880 | | nm |
| Rise time | | $V_{cc} = 5 \text{ V}, R_{L} = 1000 \Omega, I_{L} = 1 \text{ mA}$ | t _R | | 15 | | μs |
| Fall time | | | t ₌ | | 15 | | μs |

SMD2420 SERIES PHOTODIODE ABSOLUTE MAXIMUM RATINGS

| Cathode-Anode voltage | 50 V |
|--------------------------------|---------------------------------|
| Continuous device dissipation* | 125 mW |
| Operating free air range | -55° to +125°C (-67° to +257°F) |
| Storage temperature | -65° to +150°C (-85° to +302°F) |
| Soldering temperature | 260°C (500°F), 5 seconds max. |

^{*}Derate 1.43 mW/°C above 25°C ambient.

SMD2420 SERIES PHOTODIODE ELECTRICAL CHARACTERISTICS

| Parameter | Test Conditions | Sym. | Min. | Тур. | Max. | Units |
|---------------------------|--|-----------------|------|------|------|-------|
| Light current | $V_{R} = 20 \text{ V, H} = 1 \text{ mW/cm}^{2*}$ | I _L | 6 | | | μΑ |
| Dark current | $V_{R} = 20 \text{ v}, h = 0$ | I _D | | | 5 | nA |
| Reverse breakdown voltage | $I_R = 10 \mu A, H = 0$ | BV _R | 50 | | | Volts |
| Peak response wavelength | | λ | | 880 | | nm |
| Rise time | $V_{R} = 20 \text{ V}, R_{L} 100 \Omega, I_{L} = 10 \mu\text{A}$ | t _R | | 20 | | ns |
| Fall time | | $t_{_{\rm F}}$ | | 20 | | ns |

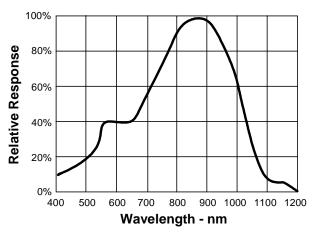
^{*}From 880 nm source

4 Honeywell • Sensing and Control

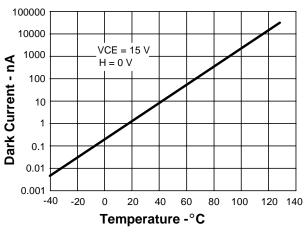
Ceramic Discrete Surface Mount

TYPICAL SMD2440 AND SMD2420 SERIES PERFORMANCE CHARACTERISTICS (when solder mounted to PC board)

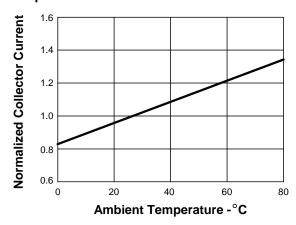
SMD2440 and SMD2420 Spectral Responsivity



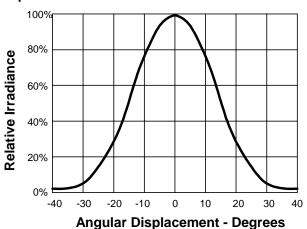
SMD2440 Dark Current vs Temperature



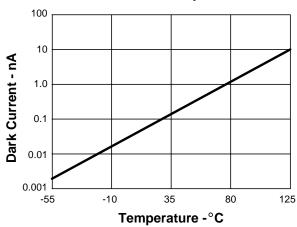
SMD2440 Collector Current vs Ambient Temperature



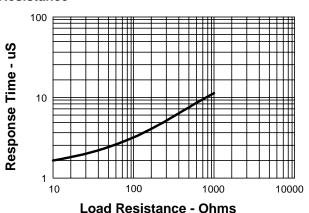
SMD2440 and SMD2420 Responsivity vs Angular **Displacement**



SMD2420 Dark Current vs Temperature



SMD2440 Non-saturated Switching Time vs Load Resistance

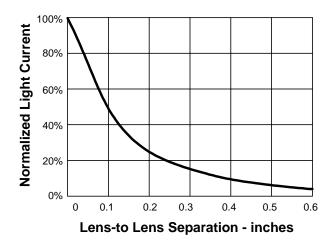


Ceramic Discrete Surface Mount

SME/SMD Series

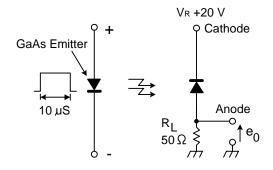
TYPICAL SMD2440 AND SMD2420 SERIES PERFORMANCE CHARACTERISTICS (when solder mounted to PC board)

SME to SMD Coupling Characteristics

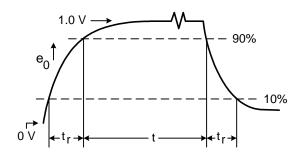


SMD2440 Switching Time Test Circuit

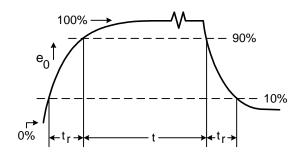
SMD2420 Switching Time Test Circuit



SMD2440 Switching Waveform



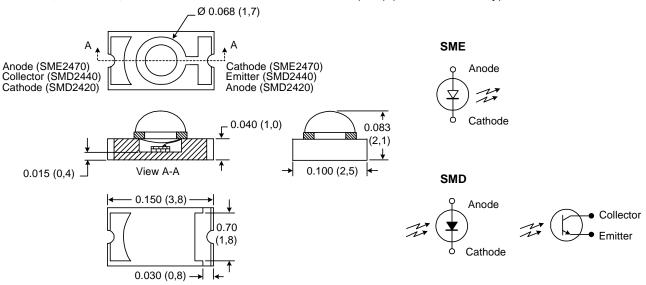
SMD2420 Switching Waveform



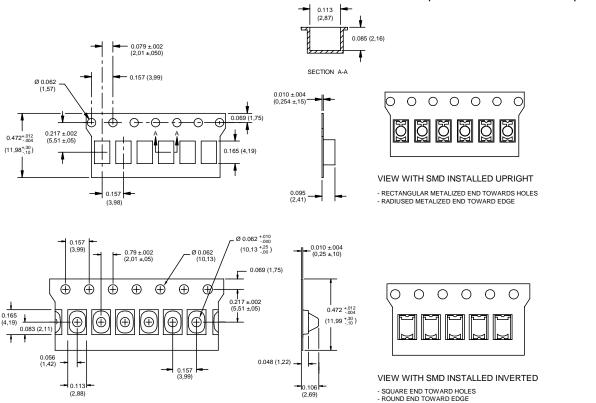
Ceramic Discrete Surface Mount

SME/SMD Series

SME2470, SMD2440, SMD2420 OUTLINE DIMENSIONS in./(mm) (for reference only)



TAPE AND REEL MOUNTING CONFIGURATIONS: EIA STD 12 mm tape and reel with a 4 mm pitch in.(mm)



Ceramic Discrete Surface Mount

SME/SMD Series

ORDER GUIDE

| Catalog Listing | Description |
|-----------------|--|
| SME2470-001 | Bulk Packaged, Surface Mount IR Emitter |
| SMD2420-001 | Bulk Packaged, Surface Mount Photodiode |
| SMD2440-001 | Bulk Packaged, Surface Mount Phototransistor |
| SMD2440-002 | Bulk Packaged, Surface Mount Phototransistor |
| SME2470-011 | Tape and Reel, Inverted, Surface Mount IR Emitter |
| SMD2420-011 | Tape and Reel, Inverted, Surface Mount Photodiode |
| SMD2440-011 | Tape and Reel, Inverted, Surface Mount Phototransistor |
| SMD2440-012 | Tape and Reel, Inverted, Surface Mount Phototransistor |
| SME2470-021 | Tape and Reel Upright, Surface Mount IR Emitter |
| SMD2420-021 | Tape and Reel, Upright, Surface Mount Photodiode |
| SMD2440-021 | Tape and Reel, Upright, Surface Mount Phototransistor |
| SMD2440-022 | Tape and Reel, Upright, Surface Mount Phototransistor |

WARRANTY/REMEDY

Honeywell warrants goods of its manufacture as being free of defective material and faulty workmanship. Contact your local sales office for warranty information. If warranted goods are returned to Honeywell during that period of coverage, Honeywell will repair or replace without charge those items it finds defective. The foregoing is Buyer's sole remedy and is in lieu of all other warranties, expressed or implied, including those of merchantability and fitness for a particular purpose.

While we provide application assistance, personally, through our literature, and through the Honeywell website, it is up to the customer to determine the suitability of the product in the application.

Specifications may change at any time without notice. The information we supply is believed to be accurate and reliable as of this printing. However, we assume no responsibility for its use.

SALES AND SERVICE

Sensing and Control serves its
customers through a worldwide
network of sales offices and
distributors. For application
assistance, current specifications,
pricing or name of the nearest
Authorized Distributor, contact a
nearby sales office or call:

- TELEPHONE

— 1-800-537-6945 (USA)

_ 1-800-737-3360 (Canada)

_ 1-815-235-6847 (International)

FAX

1-815-235-6545 (USA)

INTERNET

www.honeywell.com/sensing info@micro.honeywell.com

Honeywell

HONEYWELL Sensing and Control Honeywell Inc. 11 West Spring Street Freeport, Illinois 61032

